

Low noise and low drop voltage regulator with shutdown function

Datasheet - production data



Features

- Output current up to 200 mA
- Low-dropout voltage (500 mV max. at I_{OUT} = 200 mA)
- Very low quiescent current: 0.1 μA in OFF mode and max. 250 μA in ON mode at I_{OUT} = 0 mA
- Low output noise: typ. 30 μV at I_{OUT} = 60 mA and 10 Hz < f < 80 kHz
- · Wide range of output voltages
- Internal current and thermal limit
- V_{OUT} tolerance ± 2% (at 25 °C)
- Operative input voltage from: V_{OUT} + 0.5 to 14 V (for V_{OUT} > 2 V) or from 2.5 V to 14 V (for V_{OUT} < 2 V)

Description

The LK112S is a low-dropout linear regulator with shutdown function. The internal switch can be controlled by TTL or CMOS logic levels. The device is ON when the control pin is pulled to a high logic level. An external capacitor can be connected to the noise bypass pin to reduce the output noise level to 30 $\mu Vrms$. An internal PNP pass transistor is used to achieve a low-dropout voltage.

The LK112S has a very low quiescent current in ON mode while in OFF mode the $\rm I_q$ is reduced to 100 nA max. The internal thermal shutdown circuitry limits the junction temperature below 150 °C. The load current is internally monitored and in the presence of a short-circuit or overcurrent conditions at the output, the device shuts down.

Table 1. Device summary

Part number	Output voltage
LK112SM18TR	1.8 V
LK112SM33TR	3.3 V
LK112SM50TR	5.0 V

Contents LK112S

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LK112S Diagram

1 Diagram

V_{out} V_{in} CURRENT LIMIT SHDN START-UP REFERENCE ERROR DRIVER SHUTDOWN VOLTAGE AMPLIFIER BYPASS TERM. PROTEC. O— GND CS01230

Figure 1. Schematic diagram

Pin configuration LK112S

2 Pin configuration

Figure 2. Pin connection (top view)

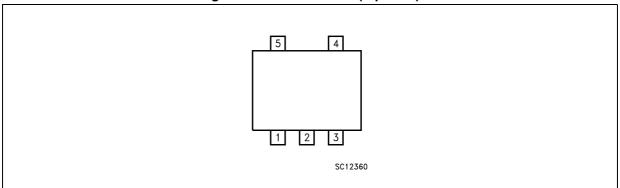


Table 2. Pin description

Pin n°	Symbol	Note
1	SHDN	Shutdown input disables the regulator when it is connected to GND or to a positive voltage lower than 0.6 V
2	GND	Ground pin: internally connected to the die attach flag to decrease the total thermal resistance and increase the package ability to dissipate power
3	Bypass	Bypass pin: 0.1 µF bypass to improve the thermal noise performance
4	OUT	Output port
5	IN	Input port

LK112S Maximum ratings

3 Maximum ratings

Table 3. Absolute maximum ratings

Symbol	Parameter	Value	Unit
VI	DC input voltage	16	V
V _{SHDN}	DC input voltage	16	V
I _O	Output current	Internally limited	
T _{STG}	Storage temperature range	-55 to 150	°C
T _{OP}	Operating junction temperature range	-40 to 125	°C

Table 4. Thermal data

Symbol	Parameter	SOT23-5L	Unit
R _{thJC}	Thermal resistance junction-case	81	°C/W
R _{thJA}	Thermal resistance junction-ambient	255	°C/W

Electrical characteristics LK112S

4 Electrical characteristics

 T_J = 25 °C, V_{IN} = V_{OUT} +1 V, I_{OUT} = 0 mA, V_{SHDN} = 1.8 V, C_I = 1 $\mu F,\,C_O$ = 2.2 $\mu F,\,C_{BYPASS}$ = 0.1 μF unless otherwise specified.

Table 5. LK112S electrical characteristics

Symbol	Parameter	Test conditions	Min.	Тур.	Max.	Unit	
	<u> </u>	ON mode (except I _{SHDN})		175	250	μΑ	
I _d	Quiescent current	OFF mode, V _I = 8 V, V _{SHDN} = 0 V		0	0.1	μΑ	
V _O	Output voltage	I _O = 30 mA	-2		+2	%	
41/	Line regulation	$V_1 = V_O + 1 \ V \text{ to } V_O + 6 \ V, \ V_O \le 5.6 \ V$		0.7	20	mV	
ΔV_{O}	Line regulation	$V_I = V_O + 1 \text{ V to } V_O + 6 \text{ V}, V_O > 5.6 \text{ V}$		0.8	40	mV	
ΔV_{O}	Load regulation	I _O = 1 to 60 mA		15	30	mV	
ΔνΟ	Load regulation	I _O = 1 to 200 mA		30	90	mV	
V	Dropout voltage	I _O = 60 mA		0.17	0.24	V	
V_d		I _O = 200 mA ⁽¹⁾		0.35	0.5	V	
I _{SC}	Short-circuit current		200			mA	
SVR	Supply voltage rejection	$V_I = V_O + 1.5 \text{ V}, C_{BYP} = 0.1 \mu\text{F}$ $C_O = 10 \mu\text{F}, f = 400 \text{ Hz}, I_O = 30 \text{ mA}$		55		dB	
eN	Output noise voltage	B= 10 Hz to 80 kHz, C_{BYP} = 0.1 μF C_{O} = 10 μF, V_{I} = V_{O} + 1.5 V, I_{O} = 60 mA		30		μVrms	
I _{SHDN}	Shutdown input current	V _{SHDN} = 1.8 V, output ON		12	35	μΑ	
V _{SHDN}	Shutdown input logic	Output ON	1.8			V	
		Output OFF			0.6		
$\Delta V_{O}/T_{J}$	Output voltage temperature coefficient	I _O = 10 mA		0.09		mV/°C	

^{1.} For versions with an output voltage higher than 2.1 V only.

Note: For versions with an output voltage lower than 2 V VIN = 2.4 V



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5 Typical characteristics

(Unless otherwise specified, T_J = 25 °C, C_I = 1 μ F, C_O = 2.2 μ F, C_{BYP} = 100 nF)

Figure 3. Output voltage vs temperature V_{out} =2.5 V

CS01240 $V_0(V)$ 2.58 2.56 2.54 2.52 2.50 2.48 $V_{I} = 3.5V$ $V_{O} = 2.5V$ $V_{SHDN} = 1.8V$ $I_{O} = 30 \text{ mA}$ 2.46 2.44 2.42 2.40 -50 -25 T_J(°C) 0 25 50 75

Figure 4. Output voltage vs temperature V_{out}=3.8 V

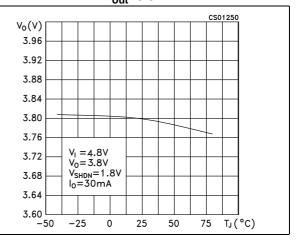


Figure 5. Line regulation vs temperature

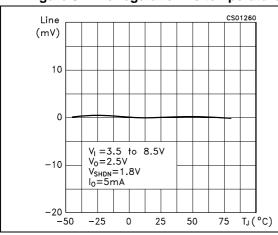


Figure 6. Load regulation vs temperature

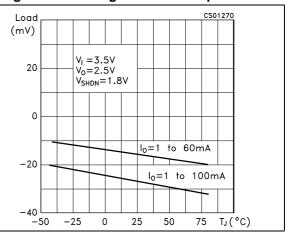
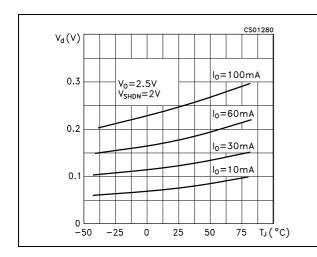


Figure 7. Dropout voltage vs temperature

Figure 8. Short-circuit current vs dropout voltage



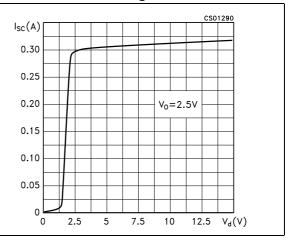
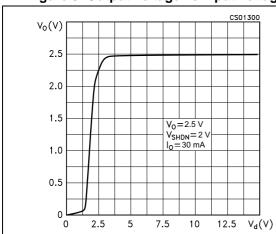


Figure 9. Output voltage vs input voltage

Figure 10. Shutdown voltage vs temperature



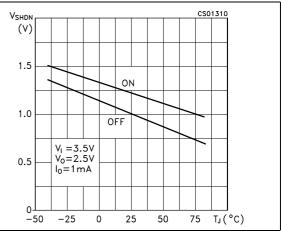
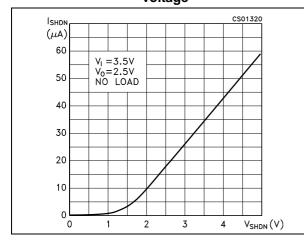
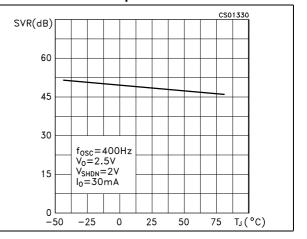


Figure 11. Shutdown current vs shutdown voltage

Figure 12. Supply voltage rejection vs temperature





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Figure 13. Supply voltage rejection vs output current

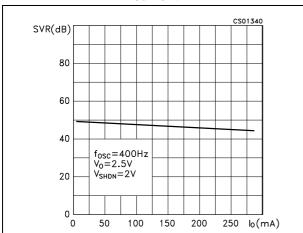


Figure 14. Supply voltage rejection vs frequency

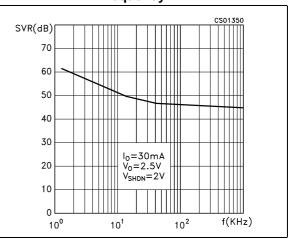


Figure 15. Supply voltage rejection vs temperature

Figure 16. Shutdown current vs temperature

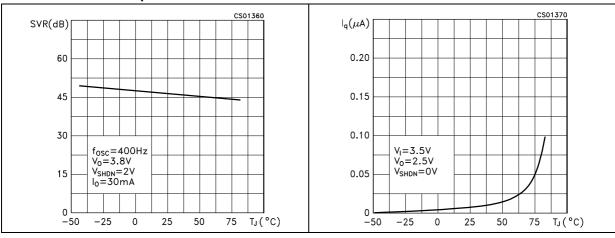


Figure 17. Quiescent current vs input voltage

Figure 18. Quiescent current vs shutdown voltage

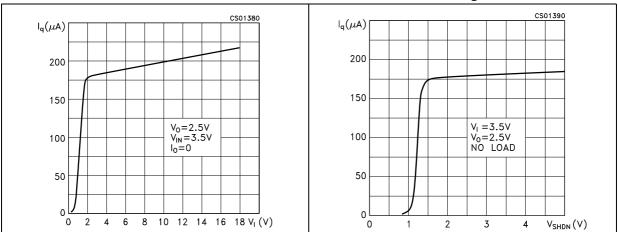
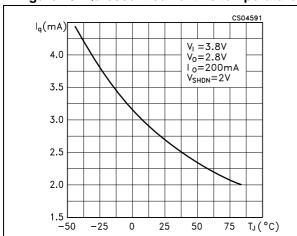


Figure 19. Quiescent current vs temperature

Figure 20. Reverse current vs reverse voltage



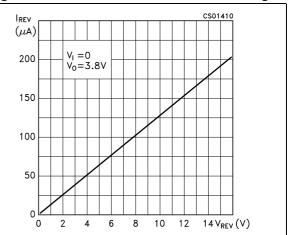
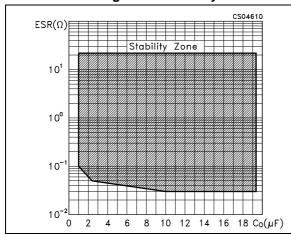


Figure 21. Stability

Figure 22. Noise spectrum



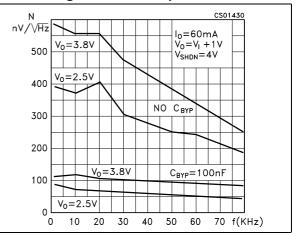
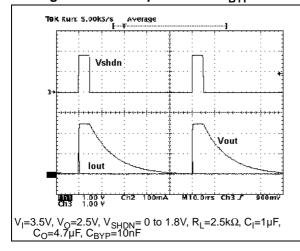
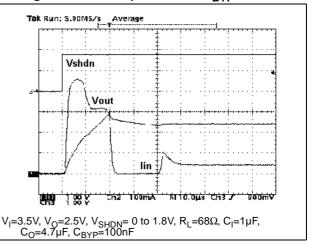


Figure 23. Start-up transient CBYP=10 nF

Figure 24. Start-up transient CBYP=100 nF





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Figure 25. Line transient Co=100 µF

Vin Vout

Figure 26. Line transient Co=10 µF

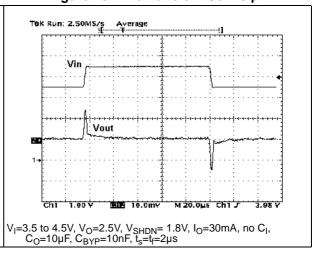


Figure 27. Line transient Co=1 µF

 $V_{I}{=}3.5$ to 4.5V, $V_{O}{=}2.5V,$ $V_{SHDN}{=}$ 1.8V, $I_{O}{=}30mA,$ no $C_{I},$ $C_{O}{=}100\mu F,$ $C_{BYP}{=}10nF,$ $t_{s}{=}t_{f}{=}2\mu s$

1.00 V 20.0mV M 20.0µs Ch1 / 3.98 V

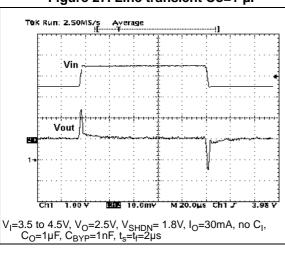


Figure 28. Load transient Vo=2.5 V, Co=2.2 µF

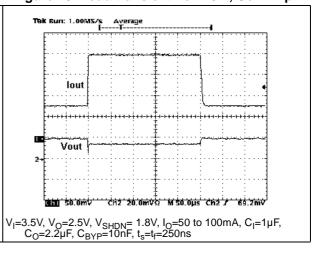


Figure 29. Load transient Vo=2.5 V, Co=10 μF

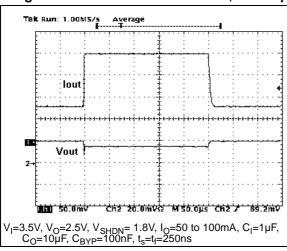
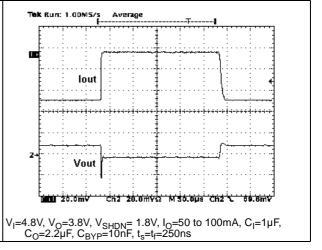


Figure 30. Load transient Vo=3.8 V,Co=2.2 μF





6 Package mechanical data

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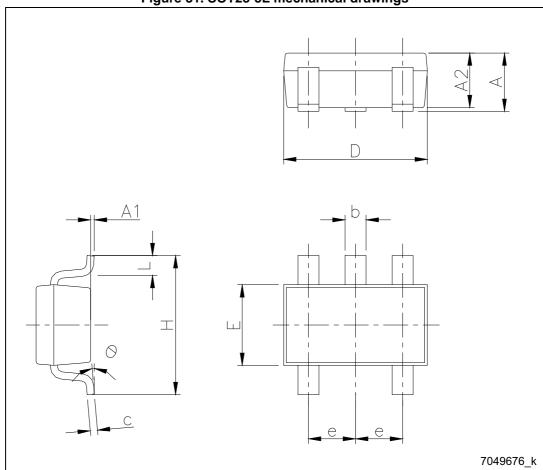
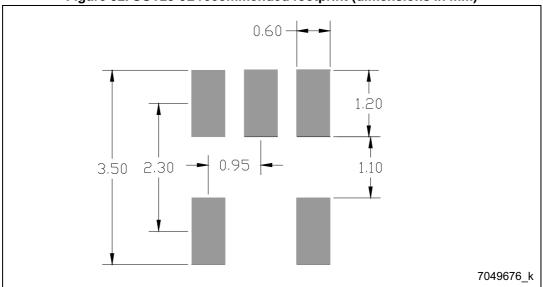


Figure 31. SOT23-5L mechanical drawings

Table 6. SOT23-5L mechanical data

Dim.	mm				
	Min.	Тур.	Max.		
А	0.90		1.45		
A1	0		0.15		
A2	0.90		1.30		
b	0.30		0.50		
С	2.09		0.20		
D		2.95			
E		1.60			
е		0.95			
Н		2.80			
L	0.30		0.60		
θ	0		8		

Figure 32. SOT23-5L recommended footprint (dimensions in mm)



7 Packaging mechanical data

A Po Note: Drawing not in scale

Figure 33.SOT23-5L tape and reel drawings

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Figure 34.SOT23-5L tape and reel mechanical data

Dim.	mm			
	Min.	Тур.	Max.	
А			180	
С	12.8	13.0	13.2	
D	20.2			
N	60			
Т			14.4	
Ao	3.13	3.23	3.33	
Во	3.07	3.17	3.27	
Ko	1.27	1.37	1.47	
Ро	3.9	4.0	4.1	
Р	3.9	4.0	4.1	



Revision history LK112S

8 Revision history

Table 7. Document revision history

Date	Revision	Changes
31-Aug-2004	3	Mistake on fig. 19.
31-Jan-2005	4	Change maturity code.
12-Jun-2006	5	Order codes updated.
17-Oct-2006	6	The T _{OP} value on table 2 updated.
20-Jul-2007	7	Add <i>Table 1</i> in cover page.
21-Sep-2007	8	Features updated.
11-Dec-2007	9	Modified: Table 6.
12-Feb-2008	10	Modified: Table 6.
10-Jul-2008	11	Modified: Table 1 and Table 6.
11-Feb-2014	12	Part number LK112Sxx changed to LK112S. Updated the title and the Description in cover page, Table 2: Pin description, Section 5: Typical characteristics and Section 6: Package mechanical data. Added Section 7: Packaging mechanical data. Minor text changes.

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